

SI-8511NVS

Surface-Mount, Synchronous Rectifier Step-down Switching Mode Regulator Control ICs

Features

- Surface-mount package (TSSOP24)
- High efficiency due to synchronous rectification: 92% (at $V_{IN} = 5V$, $I_o = 1A$, $V_o = 2.5V$)
- Capable of downsize a choke-coil due to IC's high switching frequency (400kHz typ, On Time Control). (Compared with conventional Sanken devices)
- Low reference voltage (V_{ref}) of 1.1V. The output voltage is variable from 1.1V to 6V.
- High-speed response to a load
- Compatible with low ESR capacitors
- Soft start and output ON/OFF available
- Built-in overcurrent and output-overvoltage protection circuits
- PWRGD function to indicate the output voltage status
- High precision reference voltage: $1.1V \pm 1.2\%$

Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	Ratings	Unit
Control-System DC Input Voltage	Vcc	7	V
DC Input Voltage	VIN	25	V
Boost Block Input Voltage	VH	30	V
EN Terminal Input Voltage	VEN	Vcc	V
PWRGD Terminal Applied Voltage	VPWRGD	7	V
Junction Temperature	Tj	+150	°C
Storage Temperature	Tstg	−40 to +150	°C

Applications

- Power supplies for notebook PCs and mobile devices
- Onboard local power supplies
- OA equipment
- For stabilization of the secondary-side output voltage of switching power supplies

Recommended Operating Conditions

Parameter	Symbol	Ratings	Unit
Control System Input Voltage Range	Vcc	4.5 to 5.5	V
Input Voltage Range	VIN	3 to 18	V
Output Voltage Range	Vo	1.1 to 6	V
Operating Temperature Range	Top	−20 to +85	°C

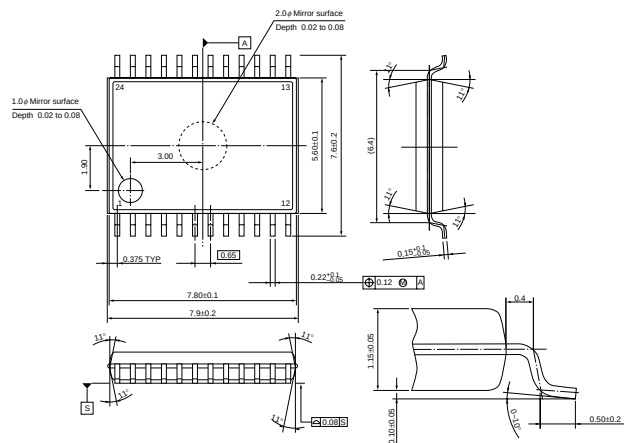
Electrical Characteristics

(Ta=25°C unless otherwise specified)

Parameter		Symbol	Ratings			Unit	Conditions
			min.	typ.	max.		
Dynamic Characteristics	Output Voltage	Vo	−1.2%	1.1	+1.2%	V	VIN=5V, Vcc=5V, VSNS connected to VO, Io=0A
	Temperature Coefficient of Output Voltage	$\Delta V_o/\Delta T$		±0.03		mV/°C	VIN=5V, Vcc=5V, VSNS connected to VO, Io=0A, Ta=0 to 85°C
Circuit Current	Circuit Current (Vcc Terminal)	Iop			6	mA	Vcc=5V, EN=H, FADJ:open
	Circuit Current (VIN Terminal)	Iop			1	mA	VIN=5V, EN=H
	Standby Current 1 (Vcc Terminal)	Istd1			100	μA	Vcc=5V, EN=L
	Standby Current 2 (VIN Terminal)	Istd2			50	μA	VIN=5V, EN=L
Undervoltage Lockout	UVLO Operating Voltage 1 (Vcc Terminal)	Vuvlo1	3.7		4.45	V	VIN=5V
	UVLO Operating Voltage 2 (VIN Terminal)	Vuvlo2	2.5		2.9	V	Vcc=5V
On Time Control	On Time	Ton		1.27		μS	Vcc=5V, VIN=5V, Vo=2.5V
	Minimum Off Time	Toff		0.7		μS	Vcc=5V
	REF Terminal Voltage	Vref	1.1	1.2	1.3	V	Vcc=5V
	REF Terminal Source Current	Iref			100	μA	Vcc=5V
High Side Drive	On Resistance (high side)	RonHH		5.5		Ω	VH-VLIN=5V
	On Resistance (low side)	RonHL		5.5		Ω	VH-VLIN=5V
Low Side Drive	On Resistance (high side)	RonLH		5.5		Ω	Vcc=5V
	On Resistance (low side)	RonLL		5.5		Ω	Vcc=5V
Bootstrap	Bootstrap Voltage	VH-VLIN	4.5	5	5.5	V	
Protection System	Current for Current Limit Detection	Ilim	90	100	110	μA	Vcc=5V, VIN=5V
	Soft Start Terminal Current	Iss		±20		μA	Vcc=5V
	EN Low Level Voltage	Vcelo	0		0.8	V	Vcc=5V
	EN High Level Voltage	Vcehi	2.4		Vcc	V	Vcc=5V
	EN Bias Level Current	ICE			5	μA	Vcc=5V, EN=5V
	PWRGD Good Voltage (high side)	Vsens		1.32		V	Vcc=5V
	PWRGD Good Voltage (low side)	Vsens		0.88		V	Vcc=5V
	PWRGD Low Output Voltage	Vpwrgd			0.4	V	Vcc=5V, Ipwrgd=120μA
	PWRGD Terminal Current	Ipwrgd			120	μA	Vcc=5V, Vpwrgd=0.4V
	PWRGD Leakage Current	Ipwrgd			5	μA	Vpwrgd=5V

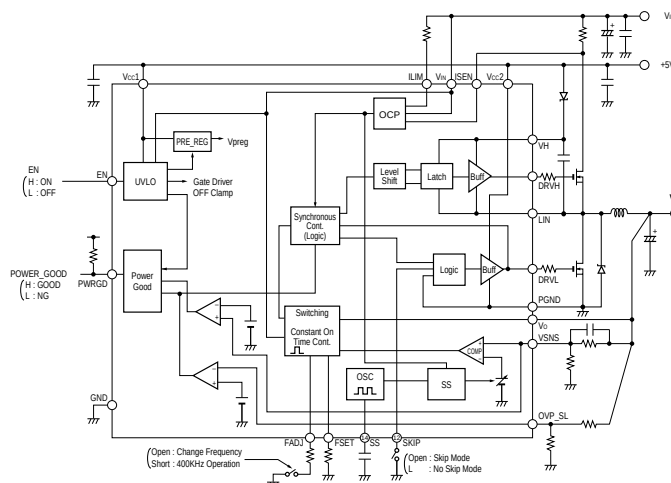
External Dimensions (TSSOP24)

(Unit : mm)

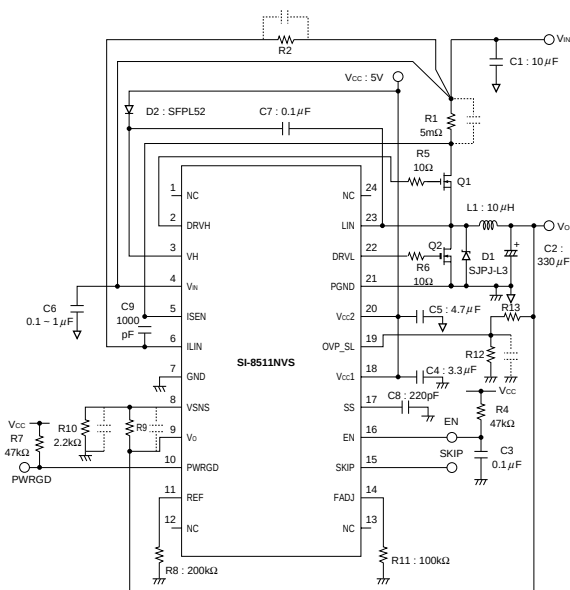


Plastic Mold Package Type
Flammability: UL94V-0
Product Mass: Approx. 1.36g

Block Diagram (Pin Assignment)



Typical Connection Diagram



MOS FET Q1, Q2

- Be sure to use logic type MOS FET as Q1 and Q2.
- If you use a normal power MOS FET type, the ON resistance may not drop to a satisfactory level due to a shortage of V_{GS} . This may deteriorate the efficiency and cause overheating.

Diode D1

- Be sure to use a Schottky-barrier diode for D1.
- If other diodes like fast recovery diodes are used, IC may be destroyed because of the reverse voltage generated by the recovery voltage or ON voltage.

Choke coil L1

- If the winding resistance of the choke coil is too high, the efficiency may drop below the rated value.
- Take care concerning heat radiation from the choke coil caused by magnetic saturation due to overload or short-circuit load.

Capacitor C1, C2

- As large ripple currents flow through C1 and C2, use high-frequency and low-impedance capacitors suitable for switching mode power supplies. Especially when the impedance of C2 is high, the switching waveform may become abnormal at low temperatures. For C2, do not use a capacitor with an extremely low equivalent series resistance (ESR) such as a ceramic capacitor, which may cause an abnormal oscillation.

* To create the optimum operating conditions, place the components as close as possible to each other.